



BTA06 and BTB06 Series

SNUBBERLESSTM, LOGIC LEVEL & STANDARD

6A TRIACs

Table 1: Main Features

| Symbol | Value | Unit |
|-------------------|-------------|------|
| $I_{T(RMS)}$ | 6 | A |
| V_{DRM}/V_{RRM} | 600 and 800 | V |
| $I_{GT}(Q_1)$ | 5 to 50 | mA |

DESCRIPTION

Available either in through-hole or surface-mount packages, the **BTA06** and **BTB06** triac series is suitable for general purpose AC switching. They can be used as an ON/OFF function in applications such as static relays, heating regulation, induction motor starting circuits... or for phase control operation in light dimmers, motor speed controllers,...

The snubberless and logic level versions (BTA/BTB...W) are specially recommended for use on inductive loads, thanks to their high commutation performances.

By using an internal ceramic pad, the BTA series provides voltage insulated tab (rated at 2500V_{RMS}) complying with UL standards (File ref.: E81734).

Table 3: Absolute Maximum Ratings

| Symbol | Parameter | Value | Unit | | |
|--------------------|---|---------------------------|---------------------------|--------------------------------|------------------|
| $I_{T(RMS)}$ | RMS on-state current (full sine wave) | TO-220AB | $T_c = 110^\circ\text{C}$ | 6 | A |
| | | TO-220AB Ins. | $T_c = 105^\circ\text{C}$ | | |
| I_{TSM} | Non repetitive surge peak on-state current (full cycle, T_j initial = 25°C) | F = 50 Hz | t = 20 ms | 60 | A |
| | | F = 60 Hz | t = 16.7 ms | 63 | |
| I^2t | I^2t Value for fusing | $t_p = 10$ ms | | 21 | A ² s |
| di/dt | Critical rate of rise of on-state current $I_G = 2 \times I_{GT}$, $t_r \leq 100$ ns | F = 120 Hz | $T_j = 125^\circ\text{C}$ | 50 | A/ μs |
| I_{GM} | Peak gate current | $t_p = 20$ μs | $T_j = 125^\circ\text{C}$ | 4 | A |
| $P_{G(AV)}$ | Average gate power dissipation | $T_j = 125^\circ\text{C}$ | | 1 | W |
| T_{stg} T_j | Storage junction temperature range Operating junction temperature range | | | - 40 to + 150 - 40 to + 125 | °C |

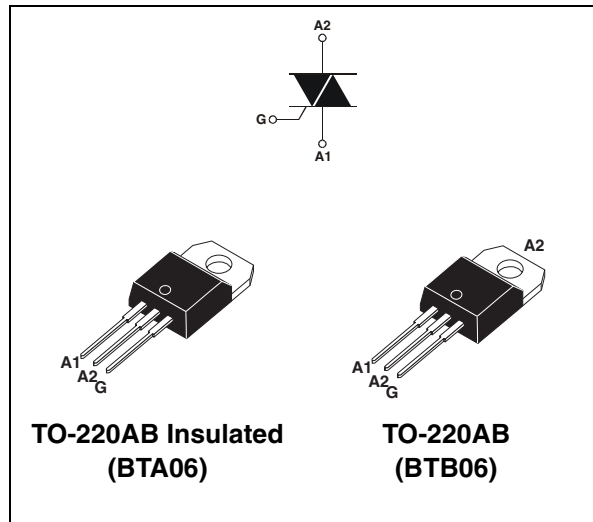


Table 2: Order Codes

| Part Number | Marking |
|---------------|----------------------------|
| BTA06-xxxxxRG | See page table 8 on page 6 |
| BTB06-xxxxxRG | |

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Tables 4: Electrical Characteristics ($T_j = 25^\circ\text{C}$, unless otherwise specified)

■ SNUBBERLESS and Logic Level (3 quadrants)

| Symbol | Test Conditions | Quadrant | | BTA06 / BTB06 | | | | Unit |
|-----------------|--|--------------|------|---------------|-----|-----|------|------------------|
| | | | | TW | SW | CW | BW | |
| I_{GT} (1) | $V_D = 12\text{ V}$ $R_L = 30\ \Omega$ | I - II - III | MAX. | 5 | 10 | 35 | 50 | mA |
| V_{GT} | | I - II - III | MAX. | 1.3 | | | | V |
| V_{GD} | $V_D = V_{DRM}$ $R_L = 3.3\ \text{k}\Omega$ $T_j = 125^\circ\text{C}$ | I - II - III | MIN. | 0.2 | | | | V |
| I_H (2) | $I_T = 100\ \text{mA}$ | | MAX. | 10 | 15 | 35 | 50 | mA |
| I_L | $I_G = 1.2 I_{GT}$ | I - III | MAX. | 10 | 25 | 50 | 70 | mA |
| | | II | | 15 | 30 | 60 | 80 | |
| dV/dt (2) | $V_D = 67\% V_{DRM}$ gate open $T_j = 125^\circ\text{C}$ | | MIN. | 20 | 40 | 400 | 1000 | V/ μs |
| $(dI/dt)_c$ (2) | $(dV/dt)_c = 0.1\ \text{V}/\mu\text{s}$ $T_j = 125^\circ\text{C}$ | | MIN. | 2.7 | 3.5 | - | - | A/ms |
| | $(dV/dt)_c = 10\ \text{V}/\mu\text{s}$ $T_j = 125^\circ\text{C}$ | | | 1.2 | 2.4 | - | - | |
| | Without snubber $T_j = 125^\circ\text{C}$ | | | - | - | 3.5 | 5.3 | |

■ Standard (4 quadrants)

| Symbol | Test Conditions | Quadrant | | BTA06 / BTB06 | | Unit |
|-----------------|---|--------------------|------|---------------|-----------|------------------|
| | | | | C | B | |
| I_{GT} (1) | $V_D = 12\text{ V}$ $R_L = 30\ \Omega$ | I - II - III IV | MAX. | 25 50 | 50 100 | mA |
| V_{GT} | | ALL | MAX. | 1.3 | | V |
| V_{GD} | $V_D = V_{DRM}$ $R_L = 3.3\ \text{k}\Omega$ $T_j = 125^\circ\text{C}$ | ALL | MIN. | 0.2 | | V |
| I_H (2) | $I_T = 500\ \text{mA}$ | | MAX. | 25 | 50 | mA |
| I_L | $I_G = 1.2 I_{GT}$ | I - III - IV | MAX. | 40 | 50 | mA |
| | | II | | 80 | 100 | |
| dV/dt (2) | $V_D = 67\% V_{DRM}$ gate open $T_j = 125^\circ\text{C}$ | | MIN. | 200 | 400 | V/ μs |
| $(dV/dt)_c$ (2) | $(dI/dt)_c = 2.7\ \text{A}/\text{ms}$ $T_j = 125^\circ\text{C}$ | | MIN. | 5 | 10 | V/ μs |

Table 5: Static Characteristics

| Symbol | Test Conditions | | | Value | Unit | |
|------------------------|--------------------------|--------------------------|---------------------------|-------|------|---------------|
| V_{TM} (2) | $I_{TM} = 8.5\ \text{A}$ | $t_p = 380\ \mu\text{s}$ | $T_j = 25^\circ\text{C}$ | MAX. | 1.55 | V |
| V_{t0} (2) | Threshold voltage | | $T_j = 125^\circ\text{C}$ | MAX. | 0.85 | V |
| R_d (2) | Dynamic resistance | | $T_j = 125^\circ\text{C}$ | MAX. | 60 | m Ω |
| I_{DRM} I_{RRM} | $V_{DRM} = V_{RRM}$ | | $T_j = 25^\circ\text{C}$ | MAX. | 5 | μA |
| | | | $T_j = 125^\circ\text{C}$ | | 1 | mA |

Note 1: minimum I_{GT} is guaranteed at 5% of I_{GT} max.

Note 2: for both polarities of A2 referenced to A1.

Table 6: Thermal resistance

| Symbol | Parameter | Value | Unit |
|---------------|-----------------------|--------------------|-----------------------------|
| $R_{th(j-c)}$ | Junction to case (AC) | TO-220AB | 1.8 |
| | | TO-220AB Insulated | 2.7 |
| $R_{th(j-a)}$ | Junction to ambient | 60 | $^{\circ}\text{C}/\text{W}$ |

Figure 1: Maximum power dissipation versus RMS on-state current (full cycle)



Figure 2: RMS on-state current versus case temperature (full cycle)

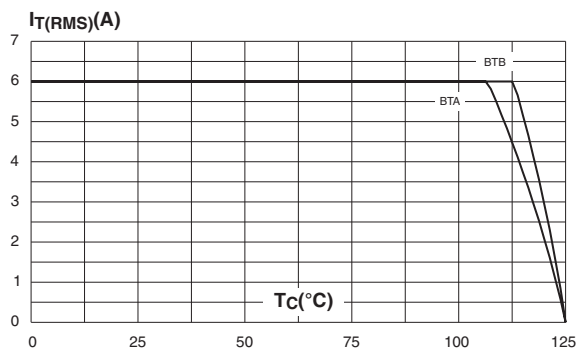


Figure 3: Relative variation of thermal impedance versus pulse duration



Figure 4: On-state characteristics (maximum values)

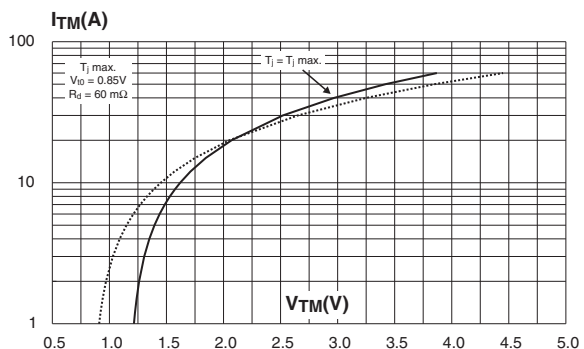


Figure 5: Surge peak on-state current versus number of cycles

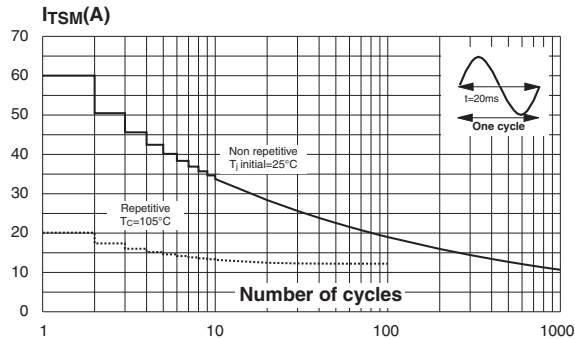


Figure 6: Non-repetitive surge peak on-state current for a sinusoidal pulse with width $t_p < 10$ ms and corresponding value of I^2t



Figure 7: Relative variation of gate trigger current, holding current and latching current versus junction temperature (typical values)

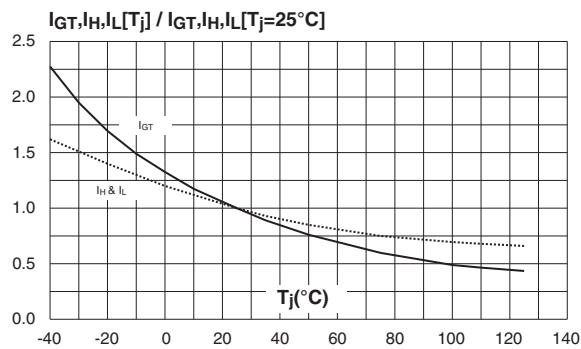


Figure 8: Relative variation of critical rate of decrease of main current versus $(dV/dt)_c$ (typical values) (Snubberless & logic level types)

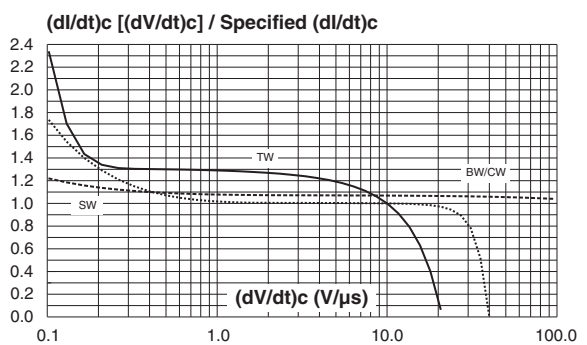


Figure 9: Relative variation of critical rate of decrease of main current versus $(dV/dt)_c$ (typical values) (Standard types)

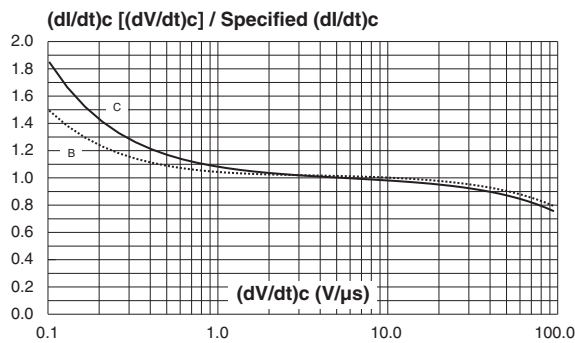


Figure 10: Relative variation of critical rate of decrease of main current versus junction temperature



Figure 11: Ordering Information Scheme



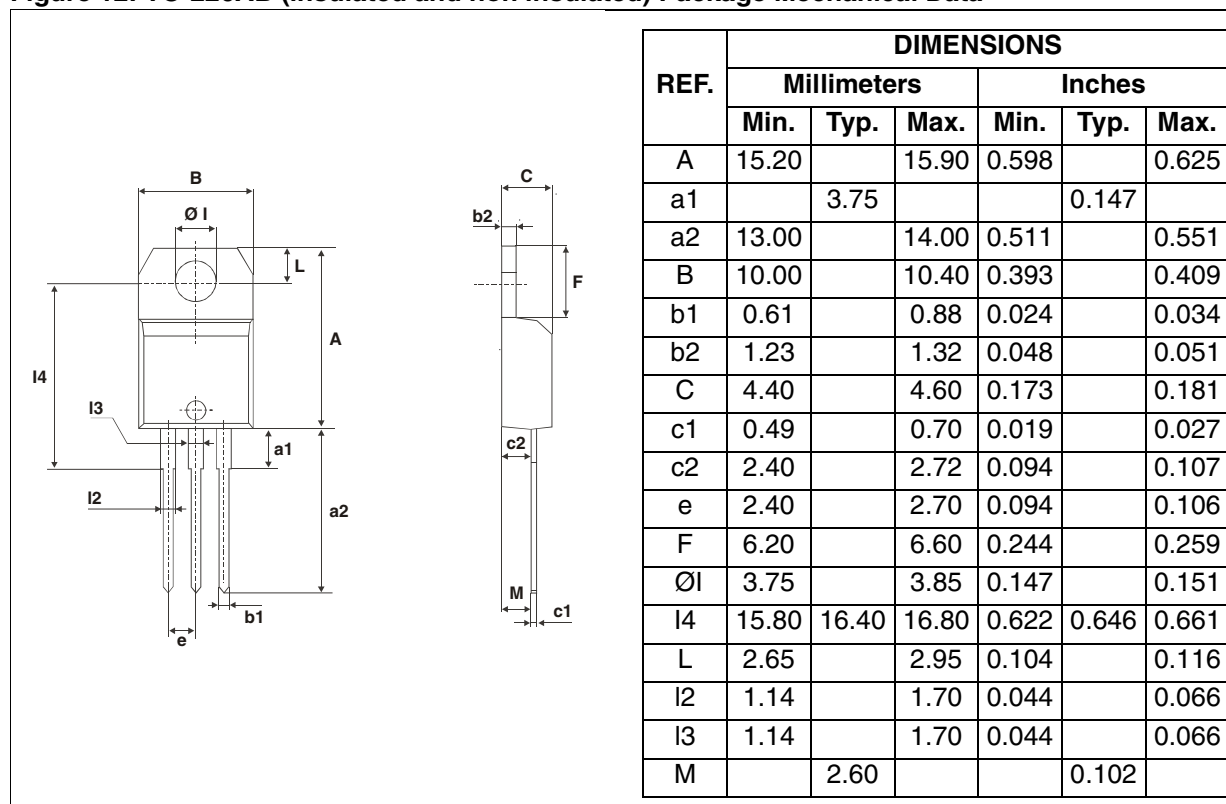
Table 7: Product Selector

| Part Number | Voltage (xxx) | | Sensitivity | Type | Package |
|-----------------|---------------|-------|-------------|-------------|----------|
| | 600 V | 800 V | | | |
| BTA/BTB06-xxxB | X | X | 50 mA | Standard | TO-220AB |
| BTA/BTB06-xxxBW | X | X | 50 mA | Snubberless | TO-220AB |
| BTA/BTB06-xxxC | X | X | 25 mA | Standard | TO-220AB |
| BTA/BTB06-xxxCW | X | X | 35 mA | Snubberless | TO-220AB |
| BTA/BTB06-xxxSW | X | X | 10 mA | Logic level | TO-220AB |
| BTA/BTB06-xxxTW | X | X | 5 mA | Logic Level | TO-220AB |

BTB: non insulated TO-220AB package

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Figure 12: TO-220AB (insulated and non insulated) Package Mechanical Data



In order to meet environmental requirements, ST offers these devices in ECOPACK® packages. These packages have a Lead-free second level interconnect. The category of second level interconnect is marked on the package and on the inner box label, in compliance with JEDEC Standard JESD97. The maximum ratings related to soldering conditions are also marked on the inner box label. ECOPACK is an ST trademark. ECOPACK specifications are available at: www.st.com.

Table 8: Ordering Information

| Ordering type | Marking | Package | Weight | Base qty | Delivery mode |
|--------------------|------------------|----------|--------|----------|---------------|
| BTA/BTB06-xxxzyzRG | BTA/BTB06-xxxzyz | TO-220AB | 2.3 g | 50 | Tube |

Note: xxx = voltage, yy = sensitivity, z = type

Table 9: Revision History

| Date | Revision | Description of Changes |
|-------------|----------|--|
| Apr-2002 | 5A | Last update. |
| 13-Feb-2006 | 6 | TO-220AB delivery mode changed from bulk to tube. ECOPACK statement added. |

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